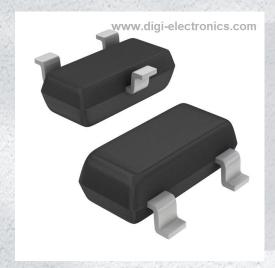


BC856ALT1G Datasheet



https://www.DiGi-Electronics.com

DiGi Electronics Part Number BC856ALT1G-DG

Manufacturer onsemi

Manufacturer Product Number BC856ALT1G

Description TRANS PNP 65V 0.1A SOT23-3

Detailed Description Bipolar (BJT) Transistor PNP 65 V 100 mA 100MHz 3

00 mW Surface Mount SOT-23-3 (TO-236)



Tel: +00 852-30501935

RFQ Email: Info@DiGi-Electronics.com

DiGi is a global authorized distributor of electronic components.



Purchase and inquiry

Manufacturer Product Number:	Manufacturer:
BC856ALT1G	onsemi
Series:	Product Status:
	Active
Transistor Type:	Current - Collector (Ic) (Max):
PNP	100 mA
Voltage - Collector Emitter Breakdown (Max):	Vce Saturation (Max) @ lb, lc:
65 V	650mV @ 5mA, 100mA
Current - Collector Cutoff (Max):	DC Current Gain (hFE) (Min) @ Ic, Vce:
15nA (ICBO)	125 @ 2mA, 5V
Power - Max:	Frequency - Transition:
300 mW	100MHz
Operating Temperature:	Mounting Type:
-55°C ~ 150°C (TJ)	Surface Mount
Package / Case:	Supplier Device Package:
TO-236-3, SC-59, SOT-23-3	SOT-23-3 (TO-236)
Base Product Number:	
BC856	

Environmental & Export classification

RoHS Status:	Moisture Sensitivity Level (MSL):
ROHS3 Compliant	1 (Unlimited)
REACH Status:	ECCN:
REACH Unaffected	EAR99
HTSUS:	
8541.21.0075	



General Purpose Transistors

PNP Silicon

BC856ALT1G Series

Features

- S and NSV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

MAXIMUM RATINGS (T_A = 25°C unless otherwise noted)

Rating	Symbol	Value	Unit
Collector-Emitter Voltage BC856, SBC856 BC857, SBC857 BC858, NSVBC858, BC859	V _{CEO}	-65 -45 -30	٧
Collector-Base Voltage BC856, SBC856 BC857, SBC857 BC858, NSVBC858, BC859	V _{CBO}	-80 -50 -30	V
Emitter-Base Voltage	V _{EBO}	-5.0	V
Collector Current - Continuous	I _C	-100	mAdc
Collector Current - Peak	Ic	-200	mAdc

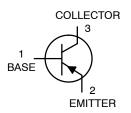
THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Total Device Dissipation FR-5 Board, (Note 1) T _A = 25°C Derate above 25°C	P _D	225 1.8	mW mW/°C
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	556	°C/W
Total Device Dissipation Alumina Substrate, (Note 2) T _A = 25°C Derate above 25°C	P _D	300 2.4	mW mW/°C
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	417	°C/W
Junction and Storage Temperature	T _J , T _{stg}	-55 to +150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1

- 1. $FR-5 = 1.0 \times 0.75 \times 0.062$ in.
- 2. Alumina = $0.4 \times 0.3 \times 0.024$ in 99.5% alumina.





SOT-23 (TO-236) CASE 318 STYLE 6

MARKING DIAGRAM



xx = Device Code

xx = (Refer to page 6)

M = Date Code*

= Pb-Free Package

(Note: Microdot may be in either location)

*Date Code orientation and/or overbar may vary depending upon manufacturing location.

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 6 of this data sheet.

ELECTRICAL CHARACTERISTICS ($T_A = 25^{\circ}C$ unless otherwise noted)

Characteristic	Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS					
Collector – Emitter Breakdown Voltage BC856, SBC856 Series (I _C = -10 mA) BC857, SBC857 Series	V _{(BR)CEO}	-65 -45	- -	_ _	V
BC858, NSBVC858 BC859 Series		-30	-	-	
Collector – Emitter Breakdown Voltage BC856 S, SBC856eries $(I_C=-10~\mu\text{A},~V_{EB}=0)$ BC857A, SBC857A, BC857B, SBC857B Only BC858, NSVB858, BC859 Series	$V_{(BR)CES}$	-80 -50 -30	- - -	- - -	V
Collector – Base Breakdown Voltage BC856, SBC856 Series (I _C = -10 μA) BC857, SBC857 Series BC858, NSVBC858, BC859 Series	V _{(BR)CBO}	-80 -50 -30	- - -	- - -	V
Emitter – Base Breakdown Voltage BC856, SBC856 Series $(I_E = -1.0 \ \mu\text{A})$ BC857, SBC857 Series BC858, NSVBC858, BC859 Series	V _{(BR)EBO}	-5.0 -5.0 -5.0	- - -	- - -	V
Collector Cutoff Current ($V_{CB} = -30 \text{ V}$) ($V_{CB} = -30 \text{ V}$, $T_A = 150^{\circ}\text{C}$)	I _{CBO}	- -	- -	-15 -4.0	nA μA
ON CHARACTERISTICS					
DC Current Gain BC856A, SBC856A, BC857A, SBC857A, BC858A $(I_C = -10~\mu\text{A}, V_{CE} = -5.0~\text{V})$ BC856B, SBC856B, BC857B, SBC856B, BC858B, NSVBC858B BC857C, SBC857C BC858C	h _{FE}		90 150 270	-	-
$(I_C = -2.0 \text{ mA}, V_{CE} = -5.0 \text{ V})$ BC856A, SBC856A, BC857A,		125	180	250	
SBC857A, BC858A BC856B, SBC856B, BC857B, SBC857B, BC858B, NSVBC858B, BC859B		220	290	475	
BC857C, SBC857C, BC858C, BC859C		420	520	800	
Collector – Emitter Saturation Voltage ($I_C = -10$ mA, $I_B = -0.5$ mA) ($I_C = -100$ mA, $I_B = -5.0$ mA)	V _{CE(sat)}			-0.3 -0.65	V
Base – Emitter Saturation Voltage ($I_C = -10$ mA, $I_B = -0.5$ mA) ($I_C = -100$ mA, $I_B = -5.0$ mA)	V _{BE(sat)}	- -	-0.7 -0.9	- -	V
Base – Emitter On Voltage ($I_C = -2.0 \text{ mA}, V_{CE} = -5.0 \text{ V}$) ($I_C = -10 \text{ mA}, V_{CE} = -5.0 \text{ V}$)	V _{BE(on)}	-0.6 -	- -	-0.75 -0.82	V
SMALL-SIGNAL CHARACTERISTICS					
Current – Gain – Bandwidth Product (I _C = –10 mA, V _{CE} = –5.0 Vdc, f = 100 MHz)	f _T	100	-	-	MHz
Output Capacitance (V _{CB} = -10 V, f = 1.0 MHz)	C _{ob}	-	-	4.5	pF
Noise Figure $ \text{(I}_{C} = -0.2 \text{ mA, V}_{CE} = -5.0 \text{ Vdc, R}_{S} = 2.0 \text{ k}\Omega, \text{f} = 1.0 \text{ kHz, BW} = 200 \text{ Hz)} \\ \text{BC856, SBC856, BC857, SBC857, BC858, NSVBC858 Series} \\ \text{BC859 Series} $	NF	- -	- -	10 4.0	dB
SWITCHING CHARACTERISTICS		-	-	-	-
Delay Time ($V_{CC} = -3.0 \text{ Vdc}$, $I_C = -10 \text{ mA}$, $I_E = -1 \text{ mA}$)	t _d	-	35	-	ns
Rise Time ($V_{CC} = -3.0 \text{ Vdc}$, $I_C = -10 \text{ mA}$, $I_E = -1 \text{ mA}$)	t _r	_	25	_	ns
Storage Time ($V_{CC} = -3.0 \text{ Vdc}$, $I_C = -10 \text{ mA}$, $I_E = -1 \text{ mA}$)	t _s	_	310	_	ns
Fall Time ($V_{CC} = -3.0 \text{ Vdc}$, $I_C = -10 \text{ mA}$, $I_E = -1 \text{ mA}$)	t _f	_	40	_	ns
, 55			<u> </u>	I	

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

BC857/BC858/BC859/SBC857/NSVBC858

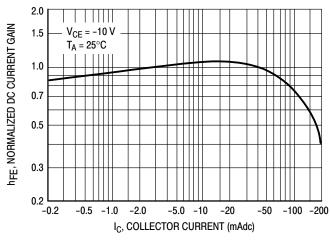


Figure 1. Normalized DC Current Gain

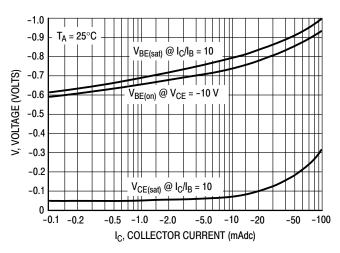


Figure 2. "Saturation" and "On" Voltages

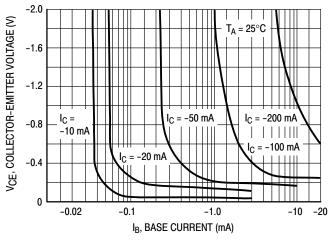


Figure 3. Collector Saturation Region

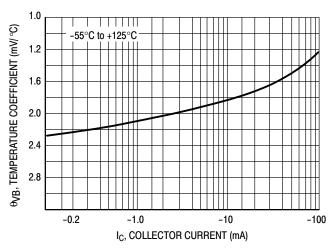


Figure 4. Base-Emitter Temperature Coefficient

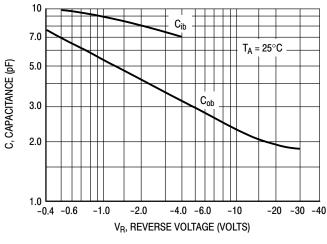


Figure 5. Capacitances

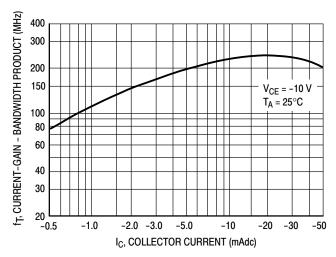


Figure 6. Current-Gain - Bandwidth Product

BC856/SBC856

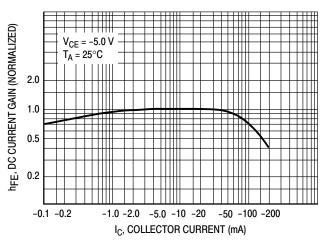


Figure 7. DC Current Gain

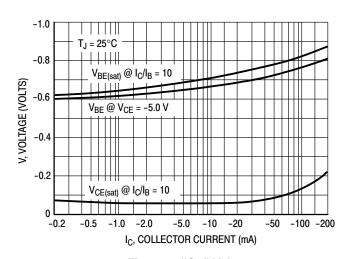


Figure 8. "On" Voltage

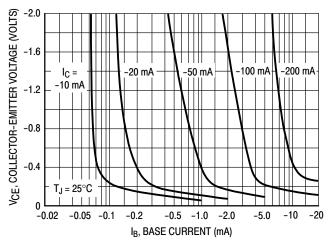


Figure 9. Collector Saturation Region

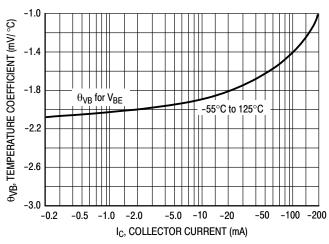


Figure 10. Base-Emitter Temperature Coefficient

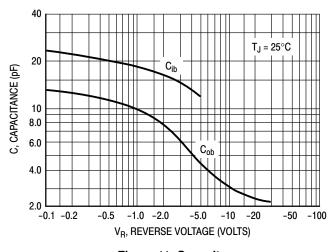


Figure 11. Capacitance

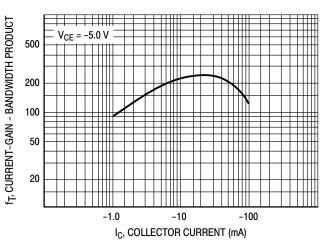


Figure 12. Current-Gain - Bandwidth Product

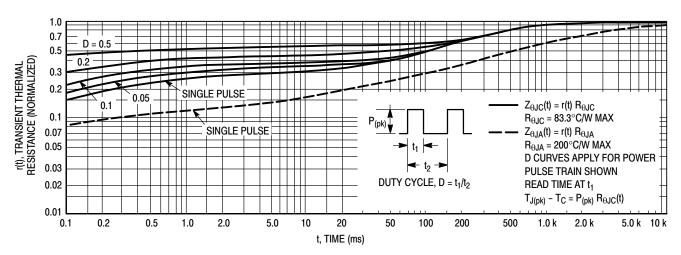


Figure 13. Thermal Response

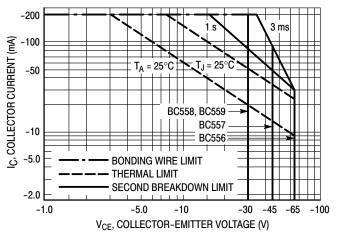


Figure 14. Active Region Safe Operating Area

The safe operating area curves indicate I_C – V_{CE} limits of the transistor that must be observed for reliable operation. Collector load lines for specific circuits must fall below the limits indicated by the applicable curve.

The data of Figure 14 is based upon $T_{J(pk)} = 150^{\circ}\mathrm{C}$; T_{C} or T_{A} is variable depending upon conditions. Pulse curves are valid for duty cycles to 10% provided $T_{J(pk)} \leq 150^{\circ}\mathrm{C}$. $T_{J(pk)}$ may be calculated from the data in Figure 13. At high case or ambient temperatures, thermal limitations will reduce the power that can be handled to values less than the limitations imposed by the secondary breakdown.

ORDERING INFORMATION

Device	Marking	Package	Shipping [†]		
BC856ALT1G	3A	SOT-23	3,000 / Tape & Reel		
SBC856ALT1G*		(Pb-Free)			
BC856ALT3G			10,000 / Tape & Reel		
BC856BLT1G	3B	SOT-23	3,000 / Tape & Reel		
SBC856BLT1G*		(Pb-Free)			
BC856BLT3G			10,000 / Tape & Reel		
SBC856BLT3G*					
BC857ALT1G	3E	SOT-23	3,000 / Tape & Reel		
SBC857ALT1G*		(Pb-Free)			
BC857BLT1G	3F	SOT-23	3,000 / Tape & Reel		
SBC857BLT1G*		(Pb-Free)			
BC857BLT3G			10,000 / Tape & Reel		
NSVBC857BLT3G*					
BC857CLT1G	3G	SOT-23	3,000 / Tape & Reel		
SBC857CLT1G*		(Pb-Free)			
BC857CLT3G			10,000 / Tape & Reel		
BC858ALT1G	3J	SOT-23 (Pb-Free)	3,000 / Tape & Reel		
BC858BLT1G	зк	SOT-23			
NSVBC858BLT1G*		(Pb-Free)			
BC858BLT3G		SOT-23 (Pb-Free)	10,000 / Tape & Reel		
BC858CLT1G	3L	SOT-23 (Pb-Free)	3,000 / Tape & Reel		
BC858CLT3G		SOT-23 (Pb-Free)	10,000 / Tape & Reel		
BC859BLT1G	4B	SOT-23 (Pb-Free)	3,000 / Tape & Reel		
BC859BLT3G		SOT-23 (Pb-Free)	10,000 / Tape & Reel		
BC859CLT1G	4C	SOT-23 (Pb-Free)	3,000 / Tape & Reel		
BC859CLT3G		SOT-23 (Pb-Free)	10,000 / Tape & Reel		

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

^{*}S and NSV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable.



MECHANICAL CASE OUTLINE

MILLIMETERS

MIN

0.89

0.01

0.37

0.08

2.80

1.20

1.78

0.30

0.35

2.10

O°

NOM

1.00

0.06

0.44

0.14

2.90

1.30

1.90

0.43

0.54

2.40

PACKAGE DIMENSIONS



SOT-23 (TO-236) 2.90x1.30x1.00 1.90P **CASE 318 ISSUE AU**

DATE 14 AUG 2024

MAX

1.11

0.10

0.50

0.20

3.04

1.40

2.04

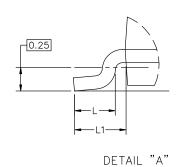
0.55

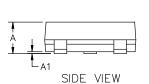
0.69

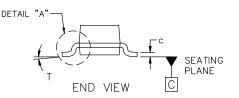
2.64

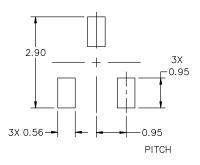
10°











Scale 3:1



DIM

Α

Α1

b

С

D

Ε

е L

L1

HE

Τ

- DIMENSIONING AND TOLERANCING 1.
- PER ASME Y14.5M, 2018. CONTROLLING DIMENSIONS: MILLIMETERS.
- MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF THE
- BASE MATERIAL.
 DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.

GENERIC MARKING DIAGRAM*



XXX = Specific Device Code

= Date Code

= Pb-Free Package

RECOMMENDED MOUNTING FOOTPRINT

* For additional information on our Pb-Free strategy and soldering details, please download the onsemi Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

STYLES ON PAGE 2

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^{*}This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "=", may or may not be present. Some products may not follow the Generic Marking.

SOT-23 (TO-236) 2.90x1.30x1.00 1.90P CASE 318 ISSUE AU

DATE 14 AUG 2024

STYLE 1 THRU 5: CANCELLED	STYLE 6: PIN 1. BASE 2. EMITTER 3. COLLECTOR	STYLE 7: PIN 1. EMITTER 2. BASE 3. COLLECTOR	STYLE 8: PIN 1. ANODE 2. NO CONNECTION 3. CATHODE	N	
STYLE 9:	STYLE 10:	STYLE 11: PIN 1. ANODE 2. CATHODE 3. CATHODE-ANODE	STYLE 12:	STYLE 13:	STYLE 14:
PIN 1. ANODE	PIN 1. DRAIN		PIN 1. CATHODE	PIN 1. SOURCE	PIN 1. CATHODE
2. ANODE	2. SOURCE		2. CATHODE	2. DRAIN	2. GATE
3. CATHODE	3. GATE		3. ANODE	3. GATE	3. ANODE
STYLE 15:	STYLE 16:	STYLE 17: PIN 1. NO CONNECTION 2. ANODE 3. CATHODE	STYLE 18:	STYLE 19:	STYLE 20:
PIN 1. GATE	PIN 1. ANODE		PIN 1. NO CONNECTION	N PIN 1. CATHODE	PIN 1. CATHODE
2. CATHODE	2. CATHODE		2. CATHODE	2. ANODE	2. ANODE
3. ANODE	3. CATHODE		3. ANODE	3. CATHODE-ANODE	3. GATE
STYLE 21:	STYLE 22:	STYLE 23:	STYLE 24:	STYLE 25:	STYLE 26:
PIN 1. GATE	PIN 1. RETURN	PIN 1. ANODE	PIN 1. GATE	PIN 1. ANODE	PIN 1. CATHODE
2. SOURCE	2. OUTPUT	2. ANODE	2. DRAIN	2. CATHODE	2. ANODE
3. DRAIN	3. INPUT	3. CATHODE	3. SOURCE	3. GATE	3. NO CONNECTION
STYLE 27: PIN 1. CATHODE 2. CATHODE 3. CATHODE	STYLE 28: PIN 1. ANODE 2. ANODE 3. ANODE				

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TECHNICAL PUBLICATIONS:

 $\textbf{Technical Library:} \ \underline{www.onsemi.com/design/resources/technical-documentation}$

onsemi Website: www.onsemi.com

ONLINE SUPPORT: www.onsemi.com/support

For additional information, please contact your local Sales Representative at

www.onsemi.com/support/sales



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